

P70FP12SN

Power MOSFETs
120V, 70A, N-channel

Feature

- N-channel
- SMD
- Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Halogen free
- Pb free terminal
- RoHS:Yes

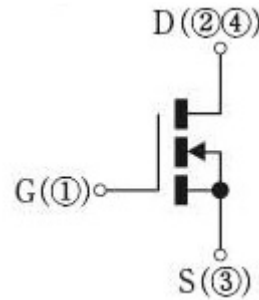
OUTLINE

Package (House Name): FP

Package (JEITA Code): SC-83 similar



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T _{stg}		-55 to 175	°C
Channel temperature	T _{ch}		-55 to 175	°C
Drain-source voltage	V _{DSS}		120	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current(DC)	I _D		70	A
Continuous drain current(Peak)	I _{DP}	Pulse width 10μs, duty=1/100	280	A
Total power dissipation	P _T		178	W
Single avalanche current	I _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	41	A
Single avalanche energy	E _{AS}	Starting T _{ch} =25°C T _{ch} ≤150°C	192	mJ

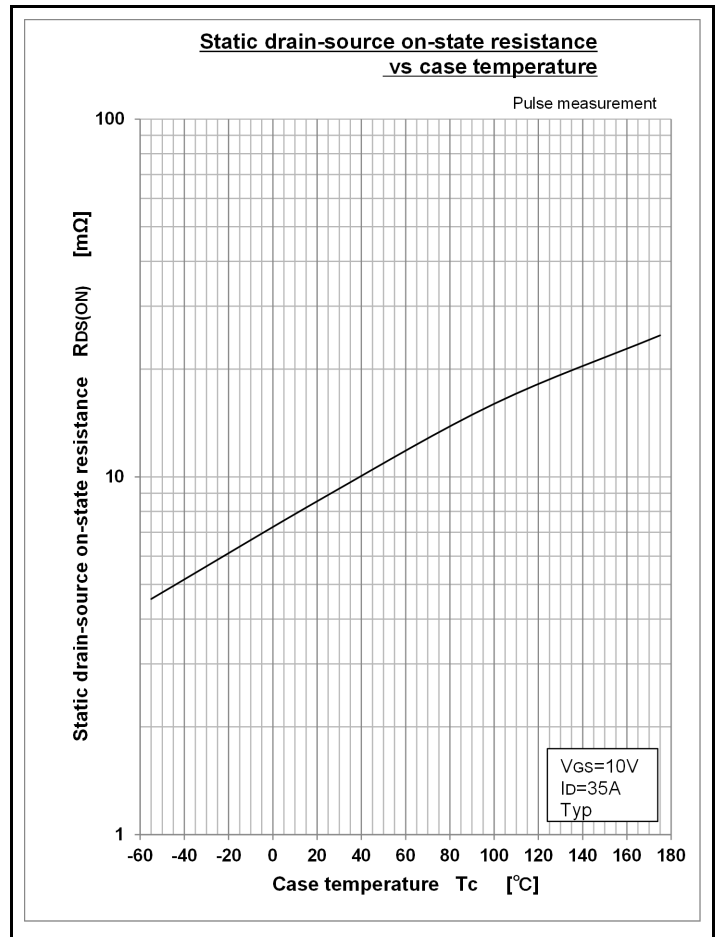
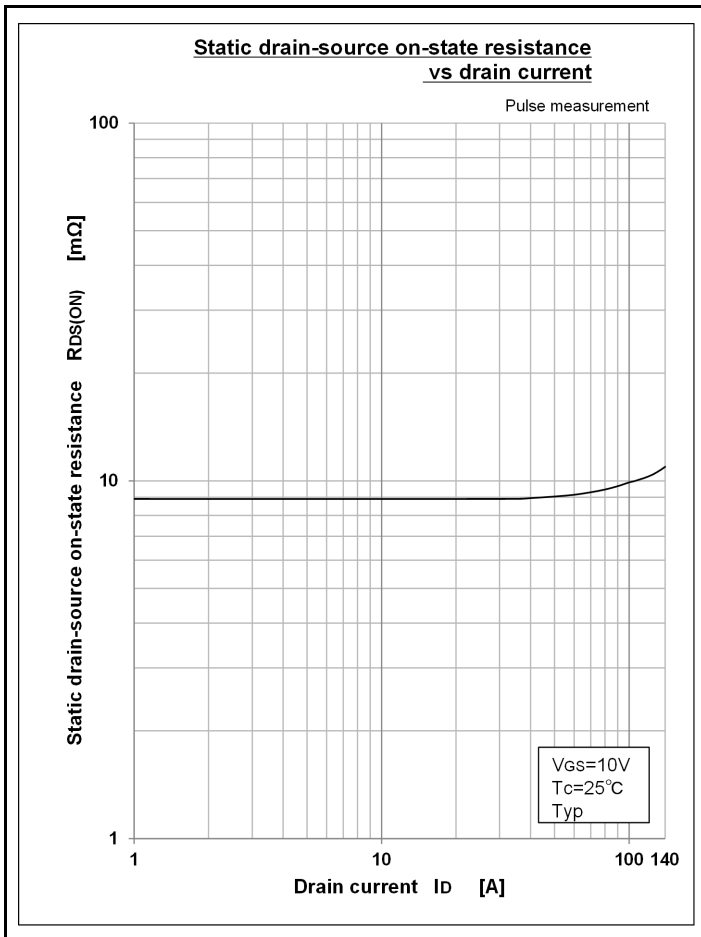
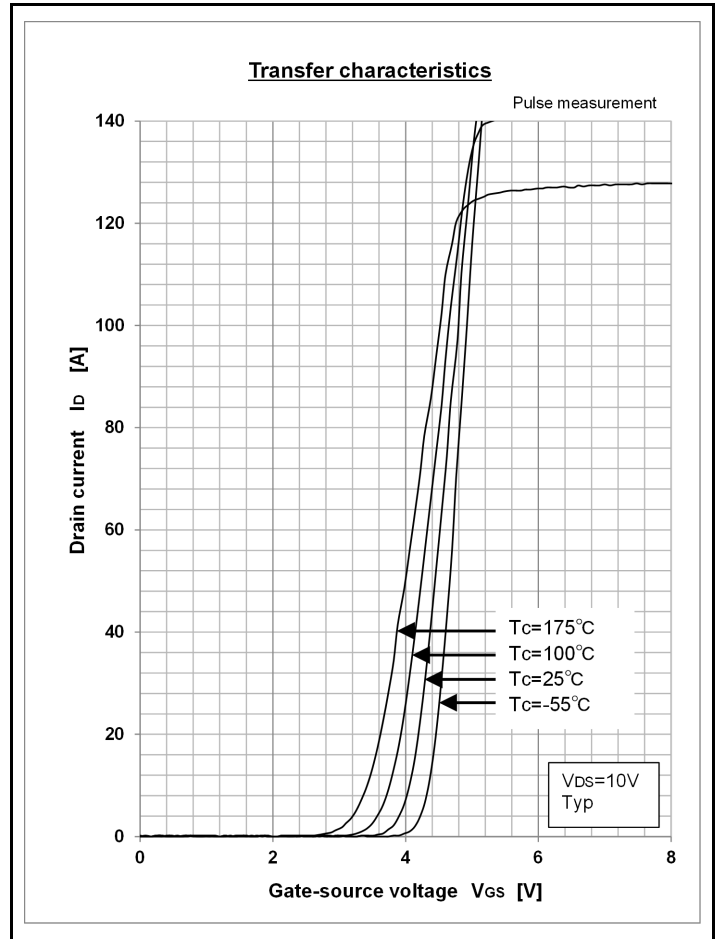
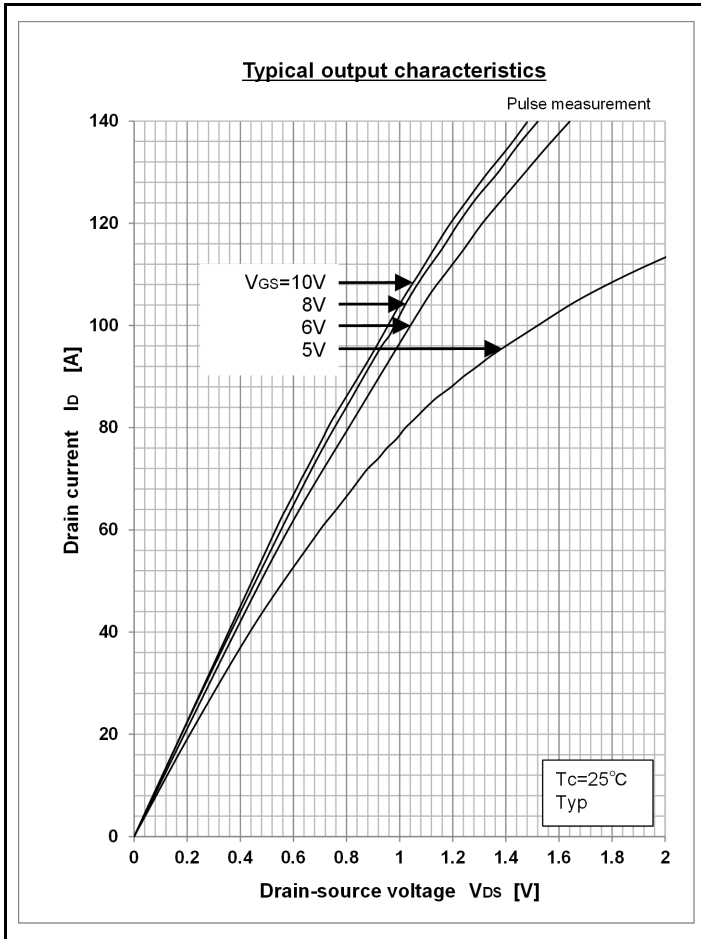
※ :See the original Specifications

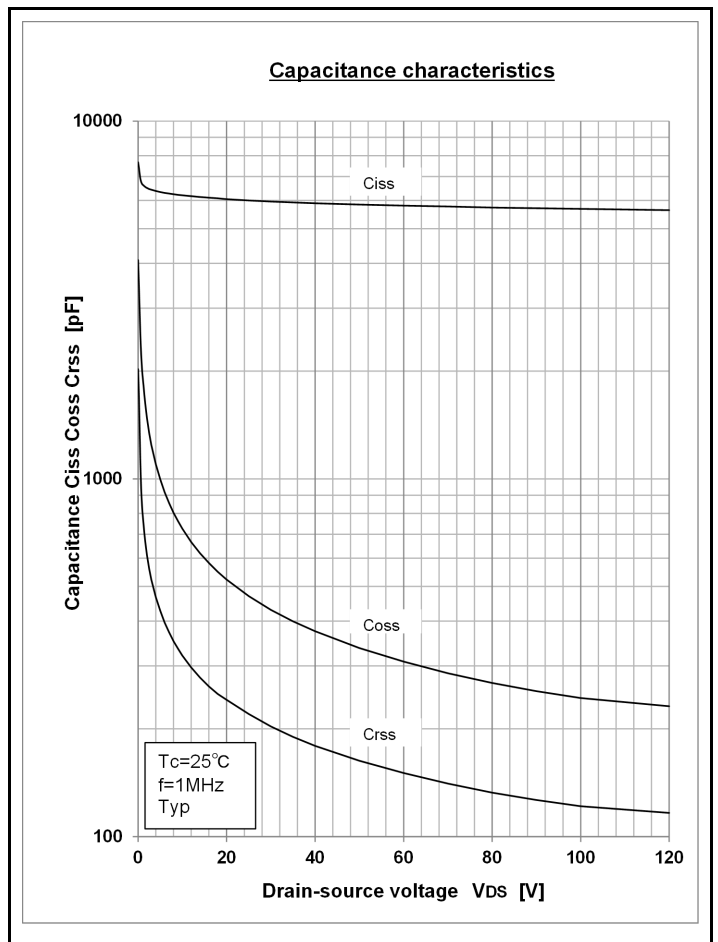
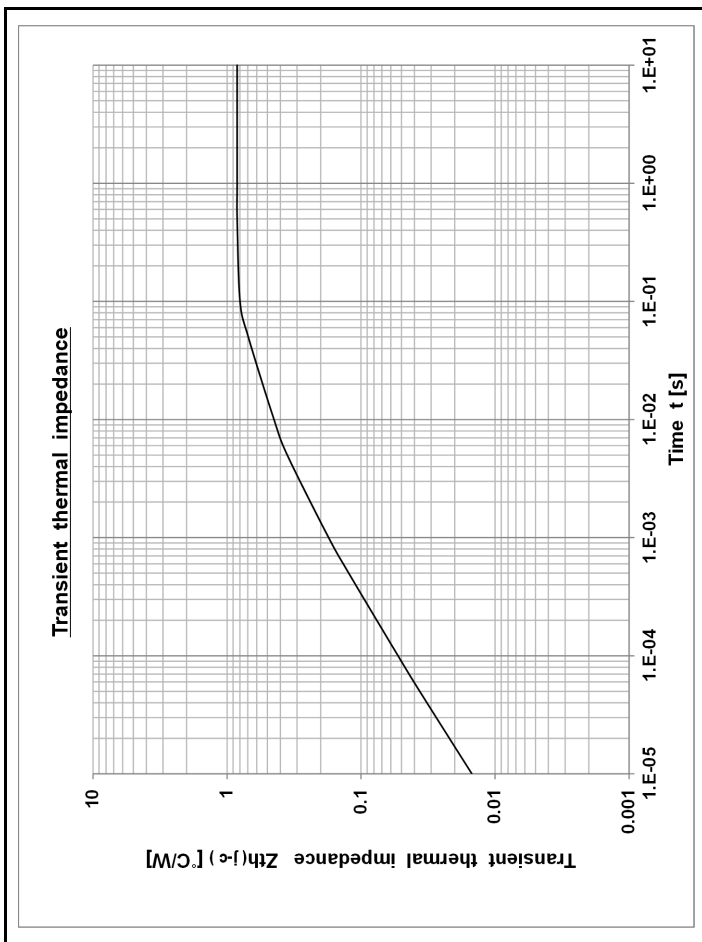
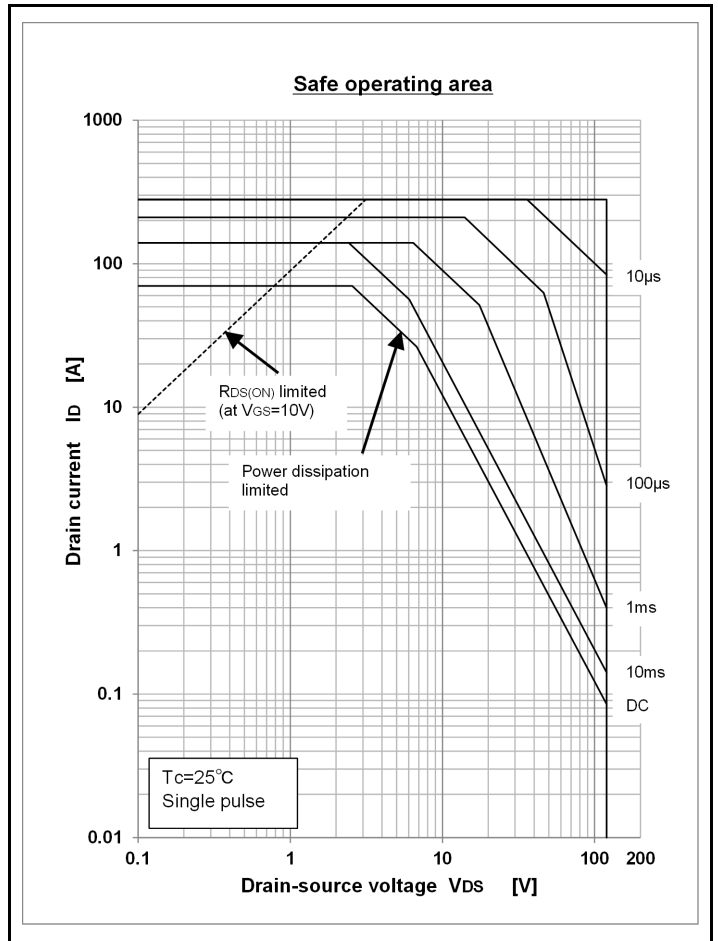
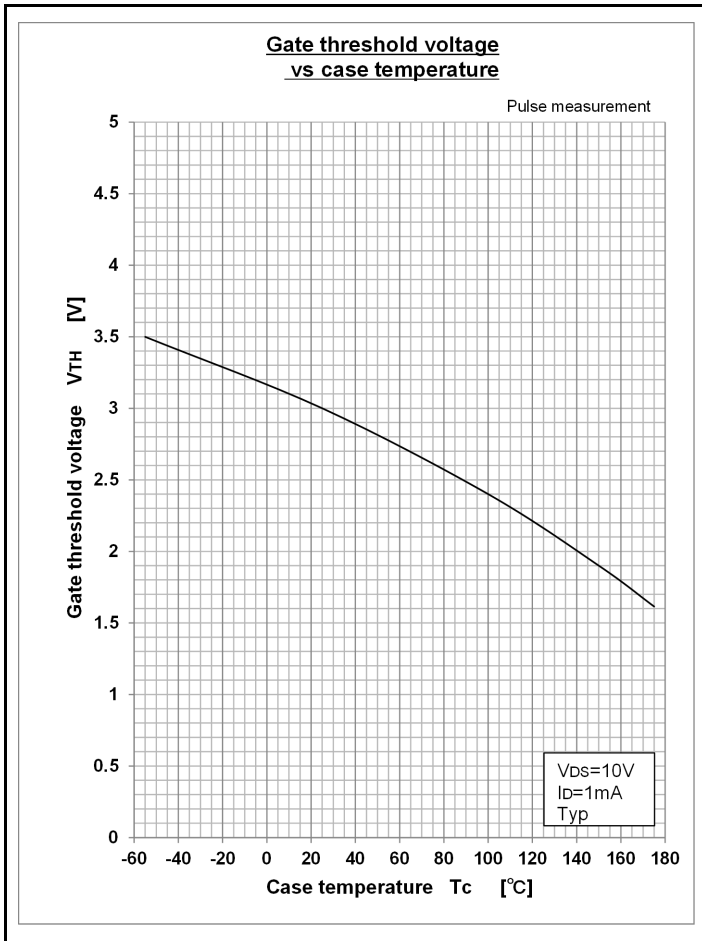
Electrical Characteristics (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	120			V
Zero gate voltage drain current	I_{DSS}	VDS=120V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=35A, VDS=10V	26			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=35A, VGS=10V		0.0089	0.0112	Ω
Gate threshold voltage	V_{th}	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=70A, VGS=0V			1.5	V
Thermal resistance	$R_{th(j-c)}$	Junction to case, with heatsink			0.84	°C/W
Total gate charge	Q_g	VDD=96V, VGS=10V, ID=70A		109		nC
Gate to source charge	Q_{gs}	VDD=96V, VGS=10V, ID=70A		29		nC
Gate to drain charge	Q_{gd}	VDD=96V, VGS=10V, ID=70A		39		nC
Input capacitance	C_{iss}	VDS=25V, VGS=0V, f=1MHz		6000		pF
Reverse transfer capacitance	C_{rss}	VDS=25V, VGS=0V, f=1MHz		220		pF
Output capacitance	C_{oss}	VDS=25V, VGS=0V, f=1MHz		470		pF
Turn-on delay time	$t_{d(on)}$	ID=35A, RL=1.71Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		9		ns
Rise time	t_r	ID=35A, RL=1.71Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		23		ns
Turn-off delay time	$t_{d(off)}$	ID=35A, RL=1.71Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		66		ns
Fall time	t_f	ID=35A, RL=1.71Ω, VDD=60V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		36		ns
Diode reverse recovery time	t_{rr}	IF=70A, VGS=0V, di/dt=100A/μs		65		ns
Diode reverse recovery charge	Q_{rr}	IF=70A, VGS=0V, di/dt=100A/μs		166		nC

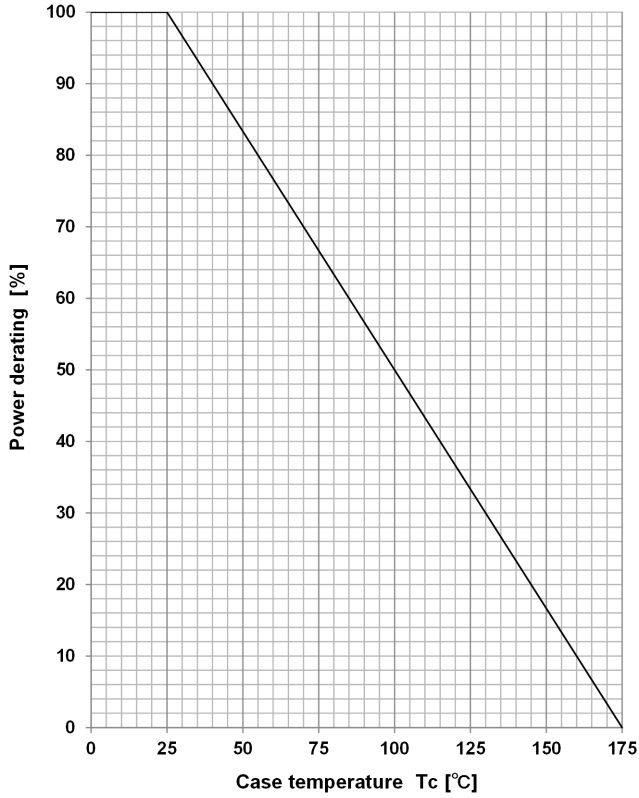
※ : See the original Specifications

CHARACTERISTIC DIAGRAMS

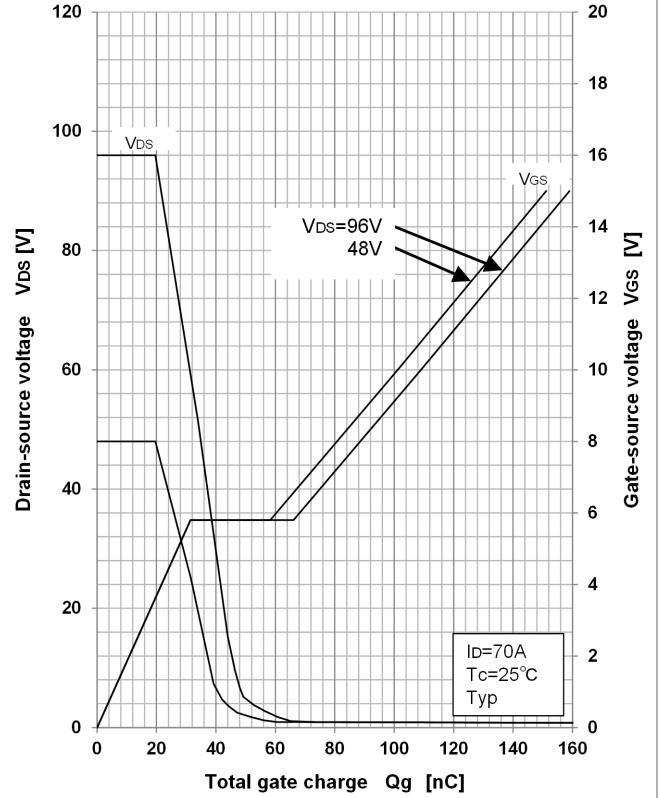




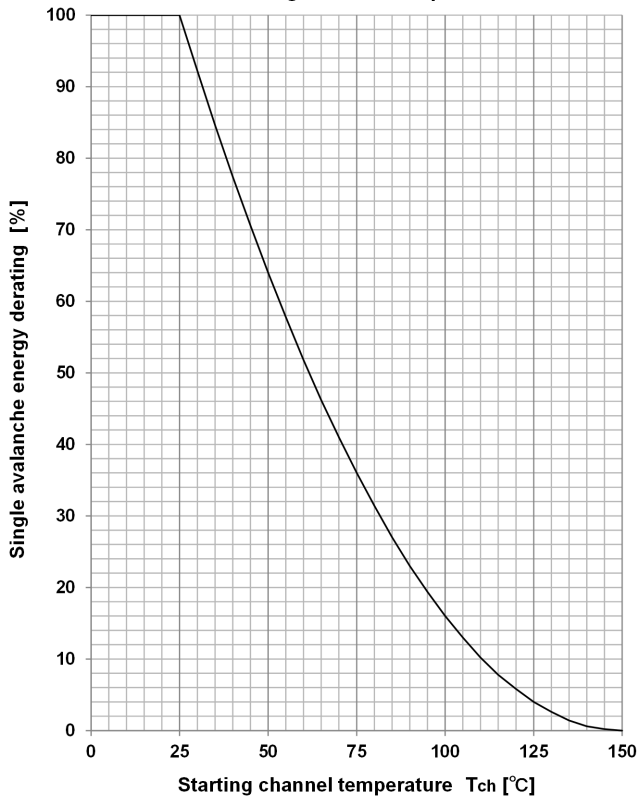
Power derating vs case temperature



Gate charge characteristics

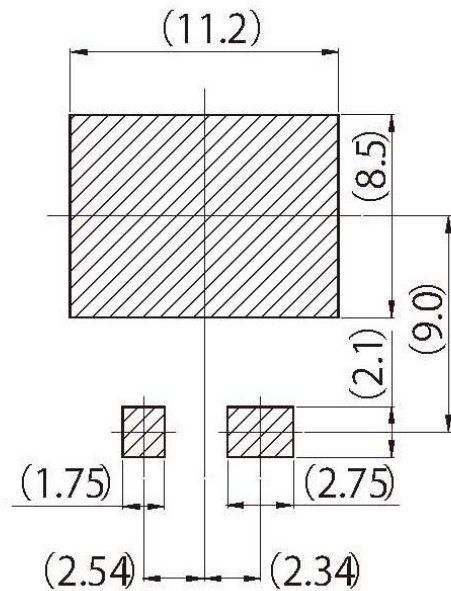
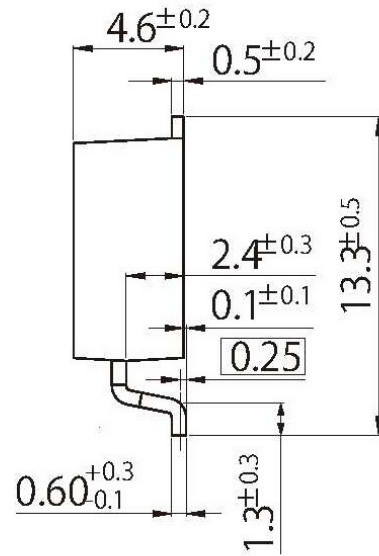
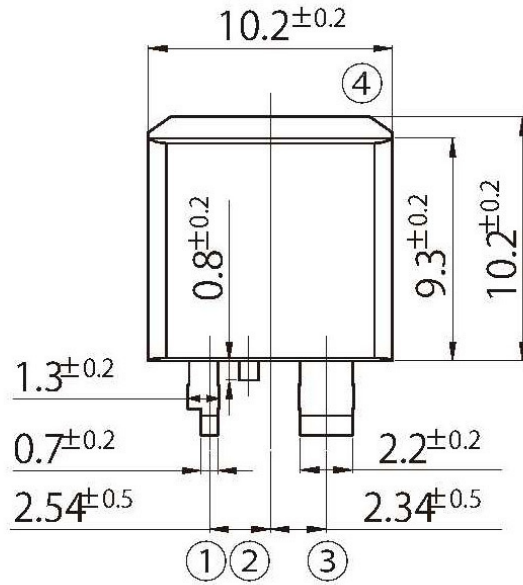


Single avalanche energy derating vs starting channel temperature



H5

JEDEC Code	-
JEITA Code	SC-83 similar
House Name	FP



• Optimize soldering pad to the board design and soldering condition.

Notes

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